

Interfacial Electronics:

observing the buried physics of magnetic
and superconducting nanostructures

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References

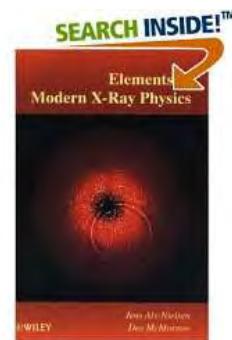
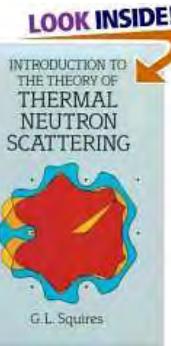
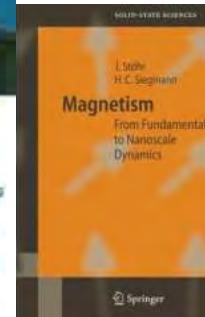
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- www.esrf.eu
- www.diamond.ac.uk



The understanding of electronic behaviour in systems with reduced dimensionality and length scale is a central theme of contemporary condensed matter physics. The unique capabilities of neutron scattering make it an ideal method to study the atomic and molecular, chemical and magnetic structure of a wide class of materials. In this review we highlight recent studies where neutron techniques have been applied to emergent materials and look forward to the possibilities enabled by instrumentation on the ISIS Second Target Station.

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<http://www.langnergroup.com>



Outline

■ Motivation

- The importance of interfaces
- Spatially resolving interfacial electronics



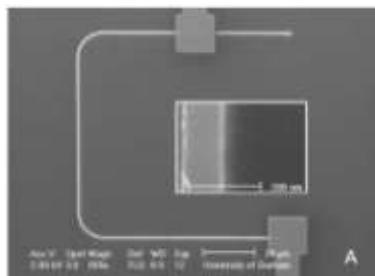
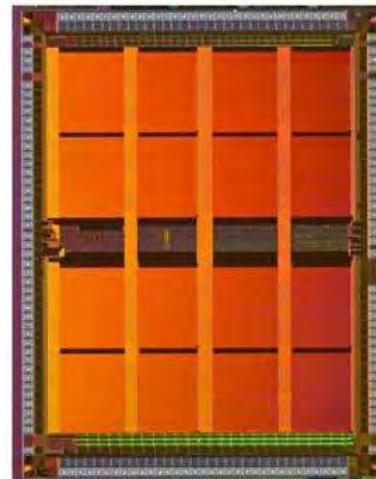
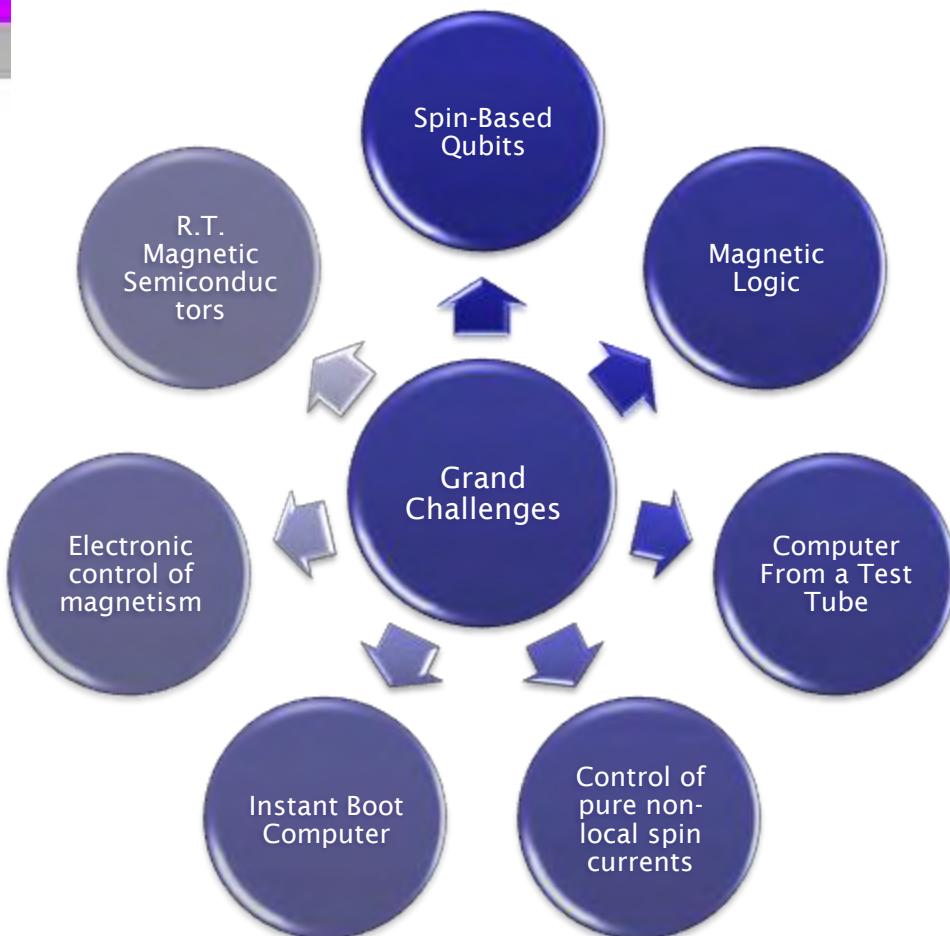
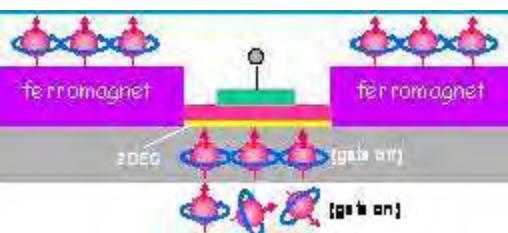
■ Interfacial effects

- A Magnetostructural Phase transition
- Nanoscale Superconductivity

■ Outlook

- Bright!

Grand Challenges: Nanomagnetism

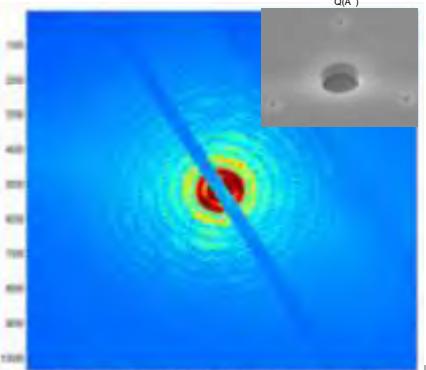
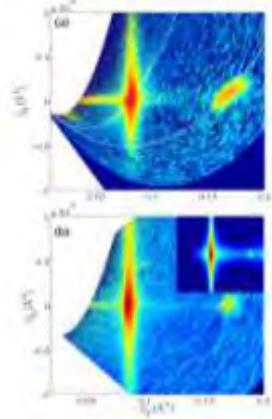


Adapted from S.D. Bader *Rev Mod Phys* 78 (2006)

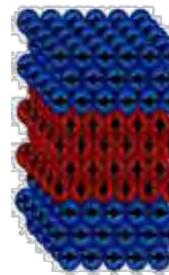
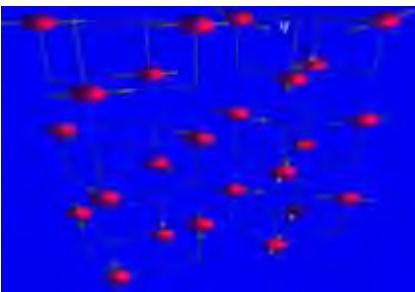
Nanoscale Electronic Phenomena Research

Heusler, DMS

Domain Structures

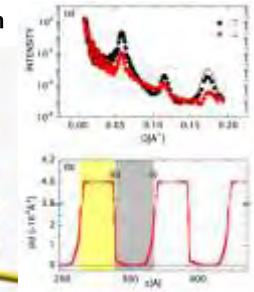


Surface Magnetism



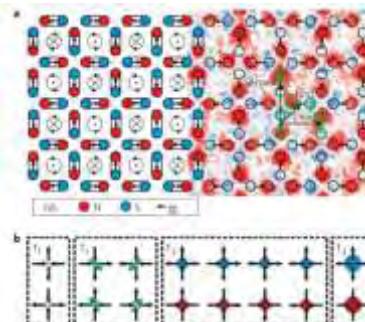
Exchange Bias

- Conventional EXB
- Synthetic EXB
- Frozen magnetism

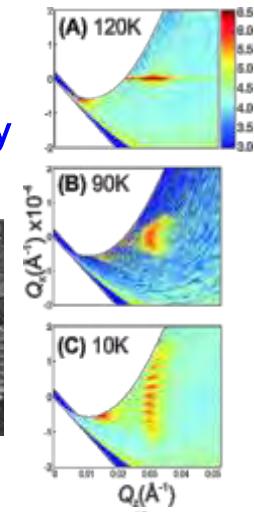
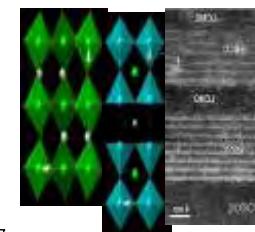


- To understand and control spin and interfacial phenomena
- Probe length scale ($<1\text{nm}$ to $>1000\text{nm}$)
- Vector Magnetometry $\sim <0.1\mu_B$ per f.u.

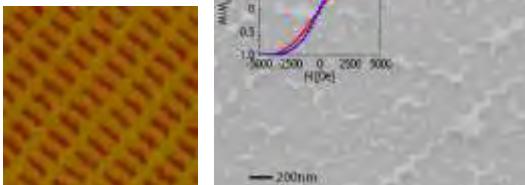
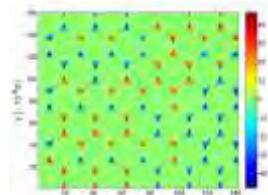
Frustration



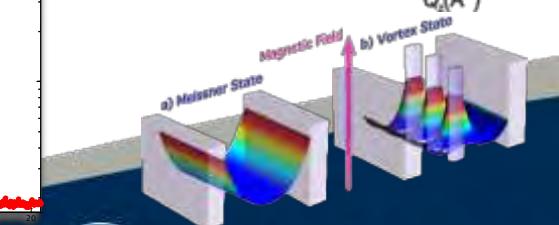
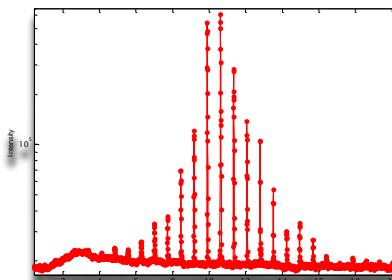
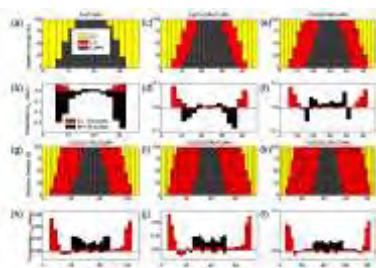
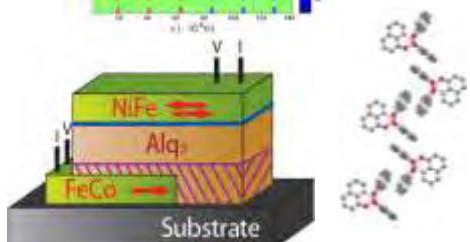
Superconductivity



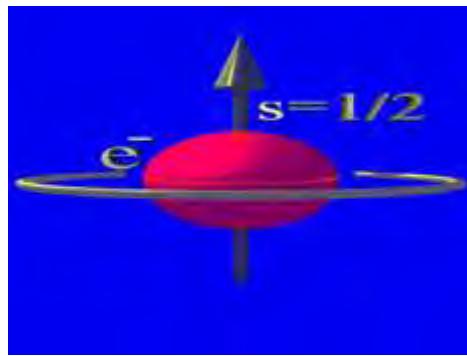
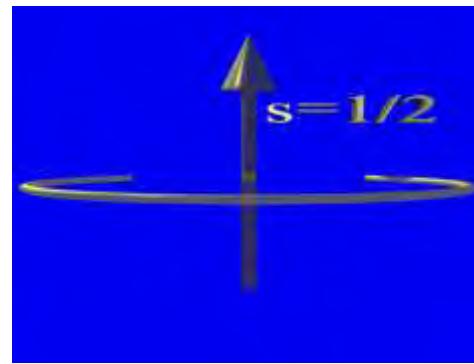
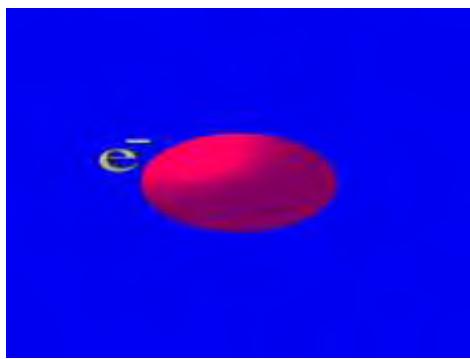
Organic Spintronics



Interfacial Magnetism



Spintronics...



- Fundamental understanding of electrons in reduced dimensions and lengthscale
- Cutting edge nanofabrication
- New physics
- Optimised functionality

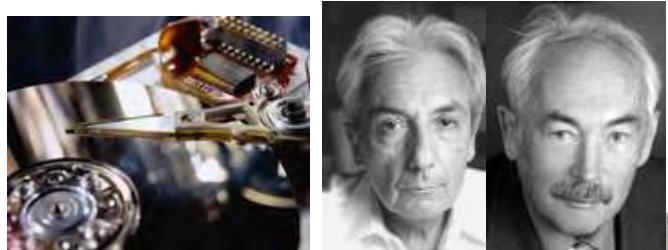
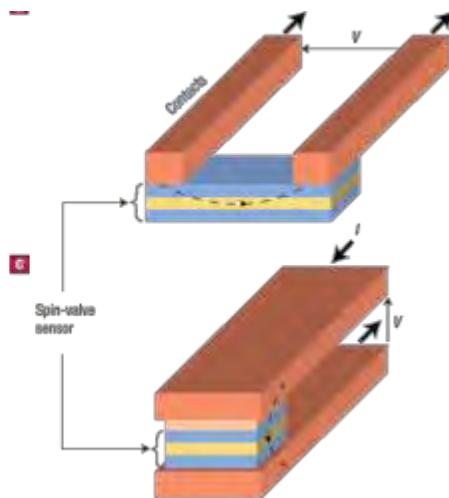
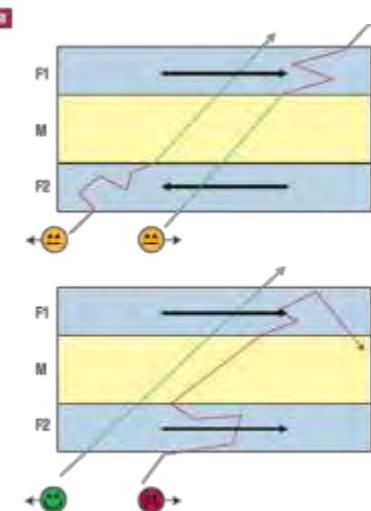
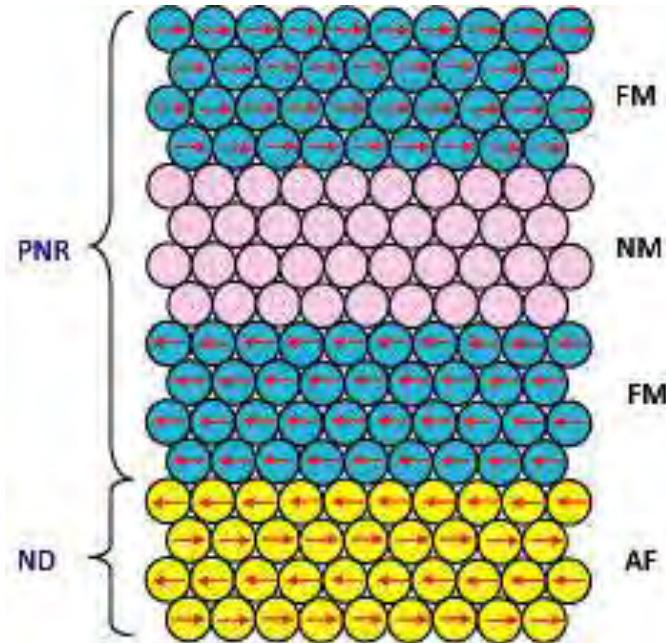
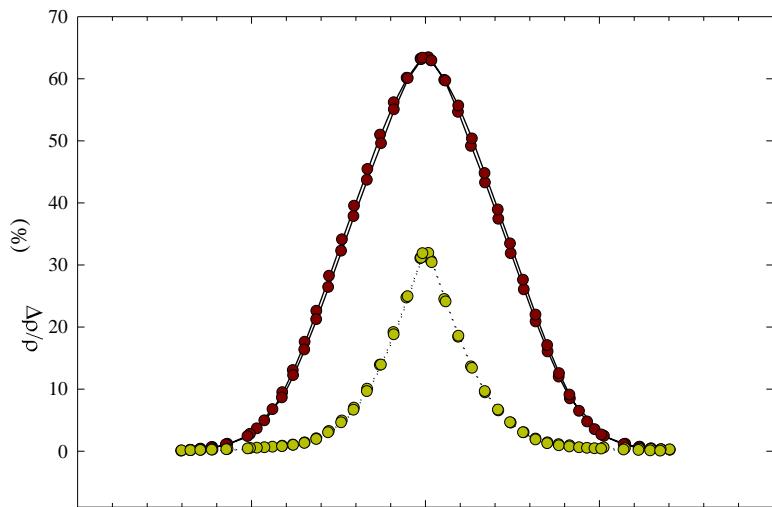
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Spintronics: a spin based electronics vision for the future
S. A. Wolf, et al. Science 294, 1488 (2001);

Quantum Well State

Co/Cu GMR

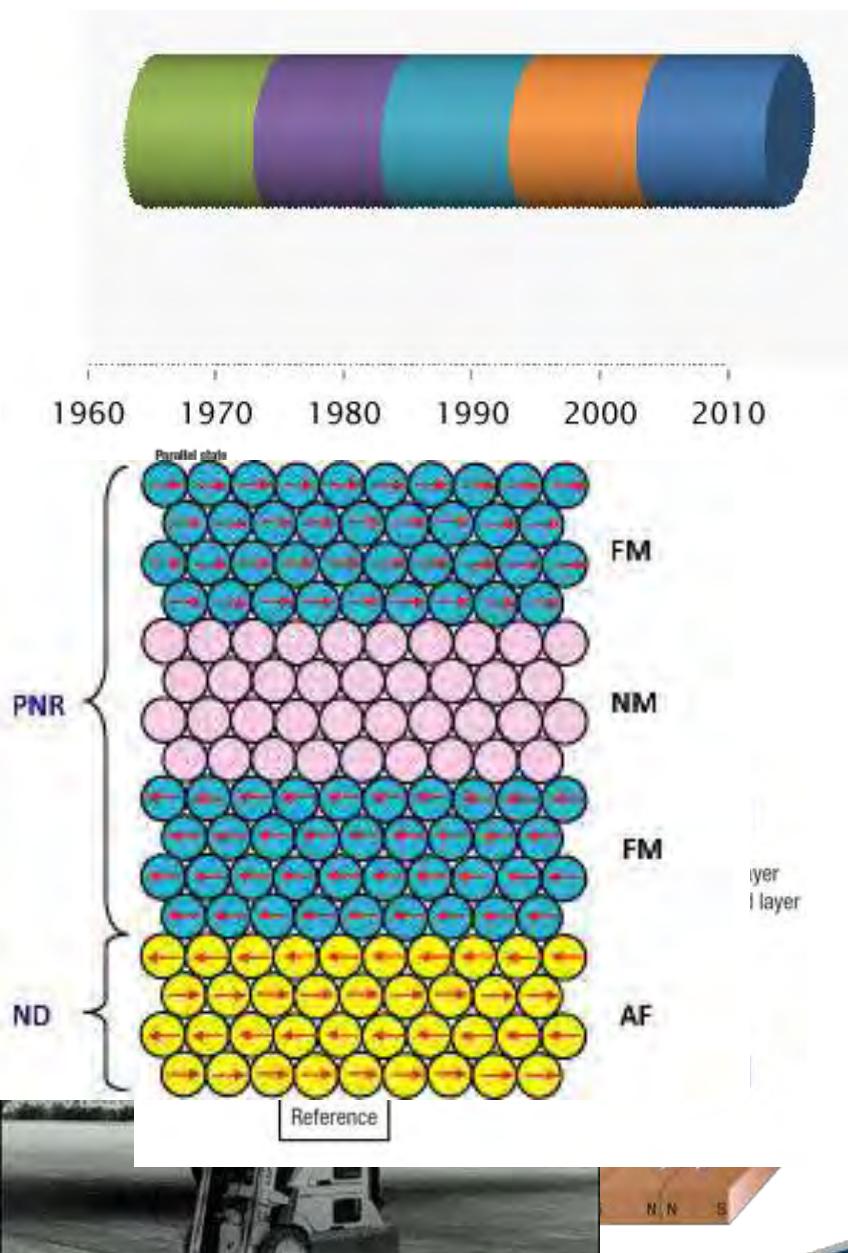
- Band matching important *e.g.* Fe/Cr



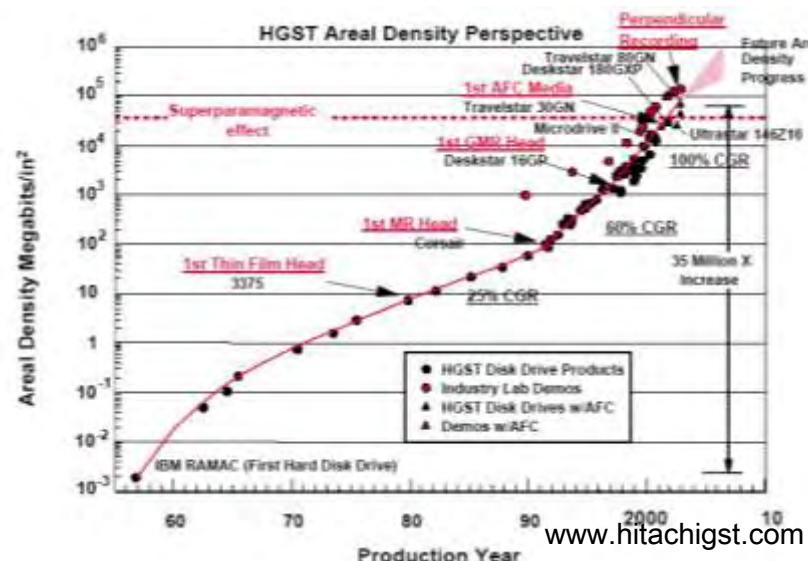
Spintronics is new?

- “... I have already communicated to the Royal Society a description of experiments by which I found that iron, when subjected to magnetic force, acquires an increase of resistance to the conduction of electricity across, the lines of magnetization...”
- William Thomson, “Effects of magnetization on the electrical conductivity of nickel and of iron” Proceedings of the Royal Society of London, Vol. 8, 1857, pp. 546550

A history of storage/spintronics

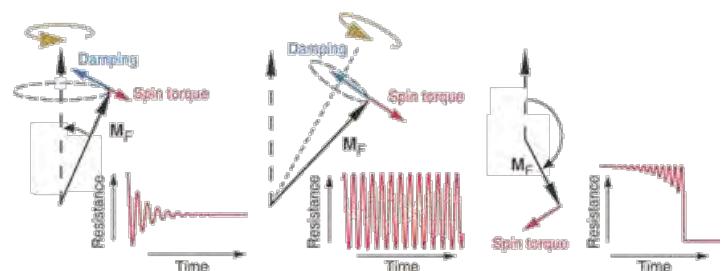
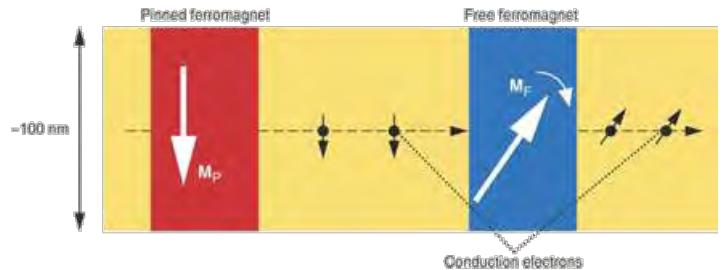


- 1988
 - Discovery of GMR
- 1991
 - Spin Valve (IBM)
- 1994
 - MTJ
- 1997
 - SV in a HDD
- 2004
 - Epitaxial MTJ
- 2005
 - MTJ Read Heads
- 2006
 - 4Mb MRAM



The Importance of interfaces

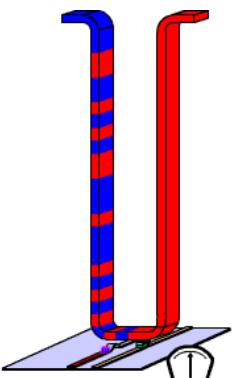
Spin Transfer Torque



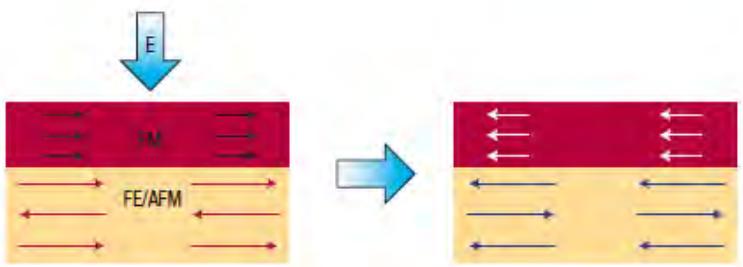
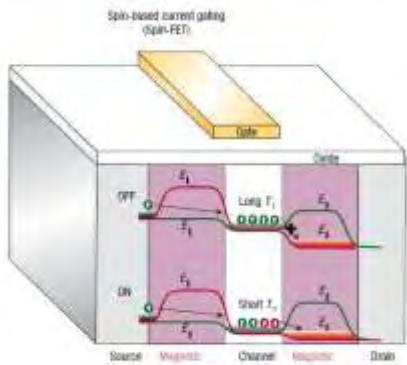
I. N. Krivorotov et al., Science 307, 228 (2005).



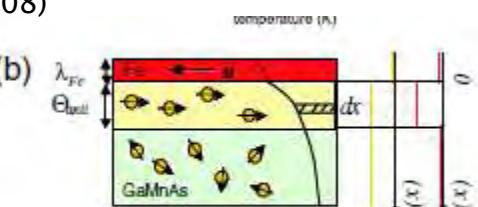
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S.S.P. Parkin et al. Science 520 5873 (2008)



Ramesh and Spaldin Nat. Mat. 6, 21 (2007)

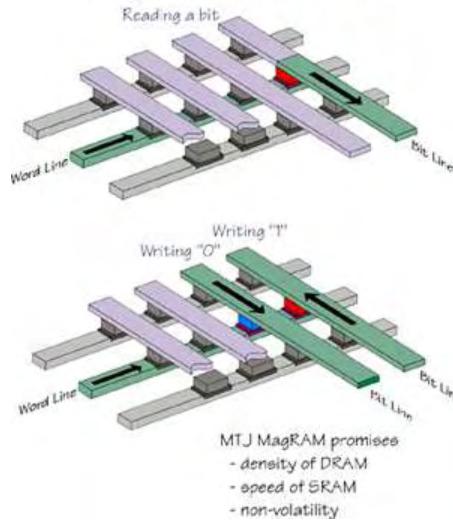


Maccherozzi et al. Phys. Rev. Lett. 101, 267201 (2008)

Awschalom and Flatté Nat. Phys. 3 153 (2007)

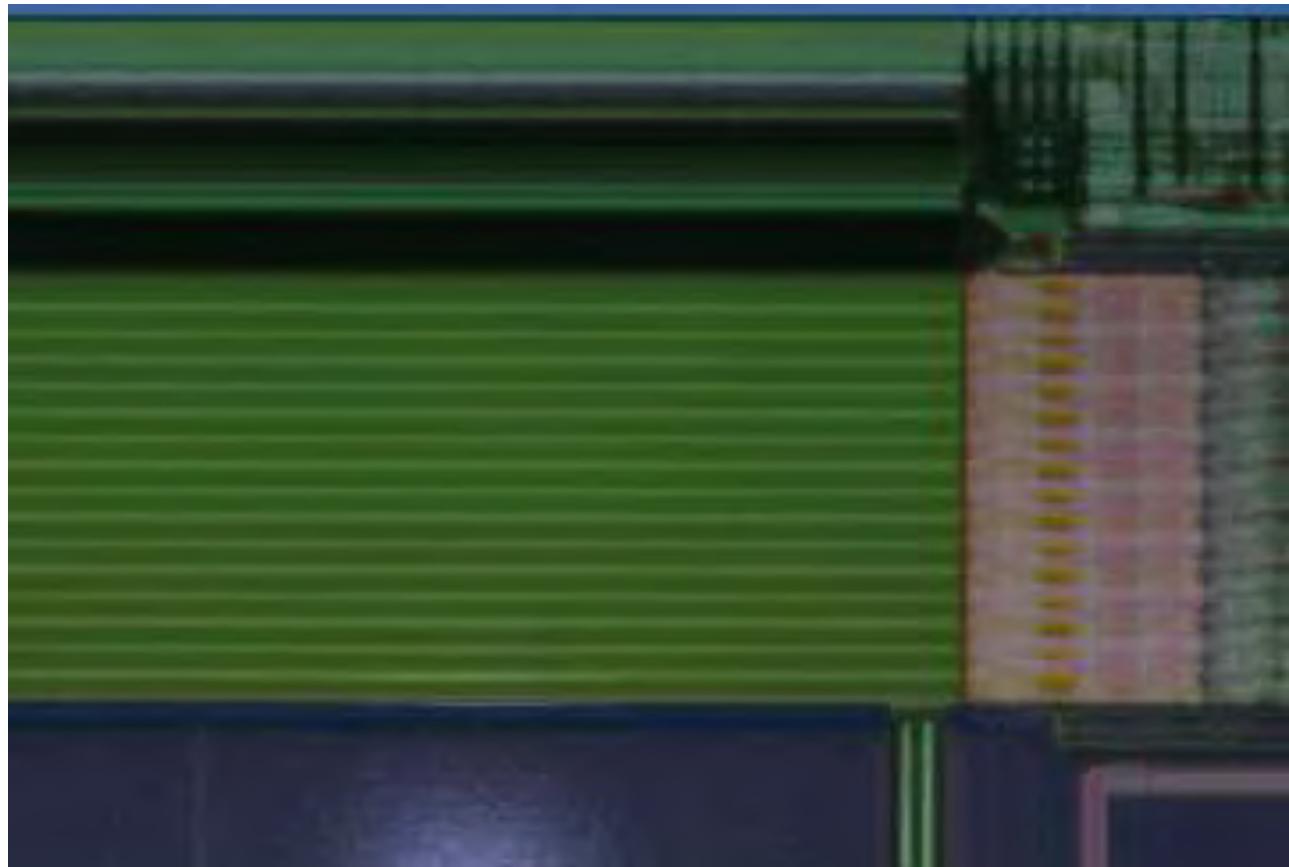
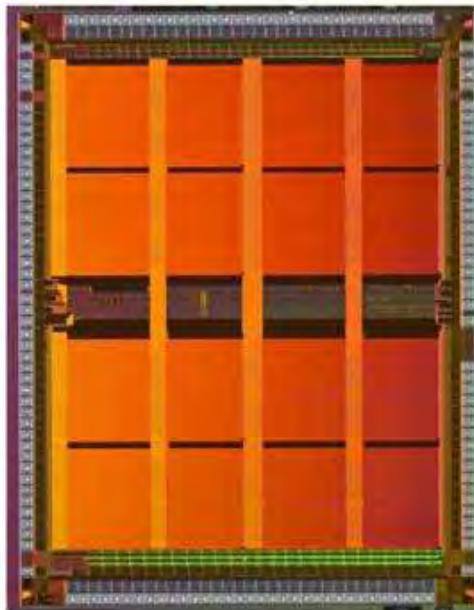
MRAM

MagRAM Architecture



MTJ MagRAM promises

- density of DRAM
- speed of SRAM
- non-volatility



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Interference effects



■ Fresnel reflection 1815



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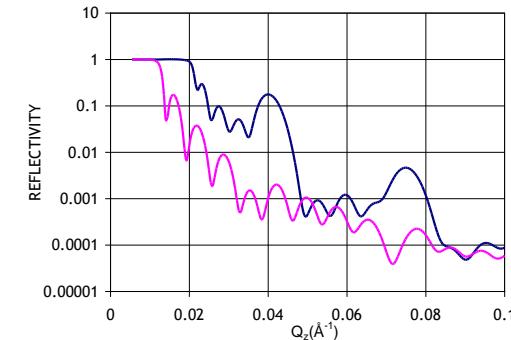
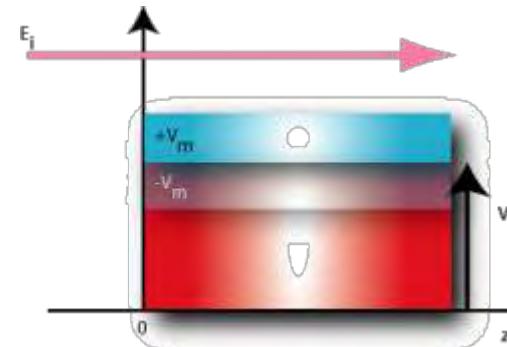
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Spin polarised Neutron Reflectivity

- Measure the reflected neutrons as a function of their perpendicular momentum and spin eigenstate

$$k^\pm = \sqrt{k - 4\pi N(b \pm cB)}$$



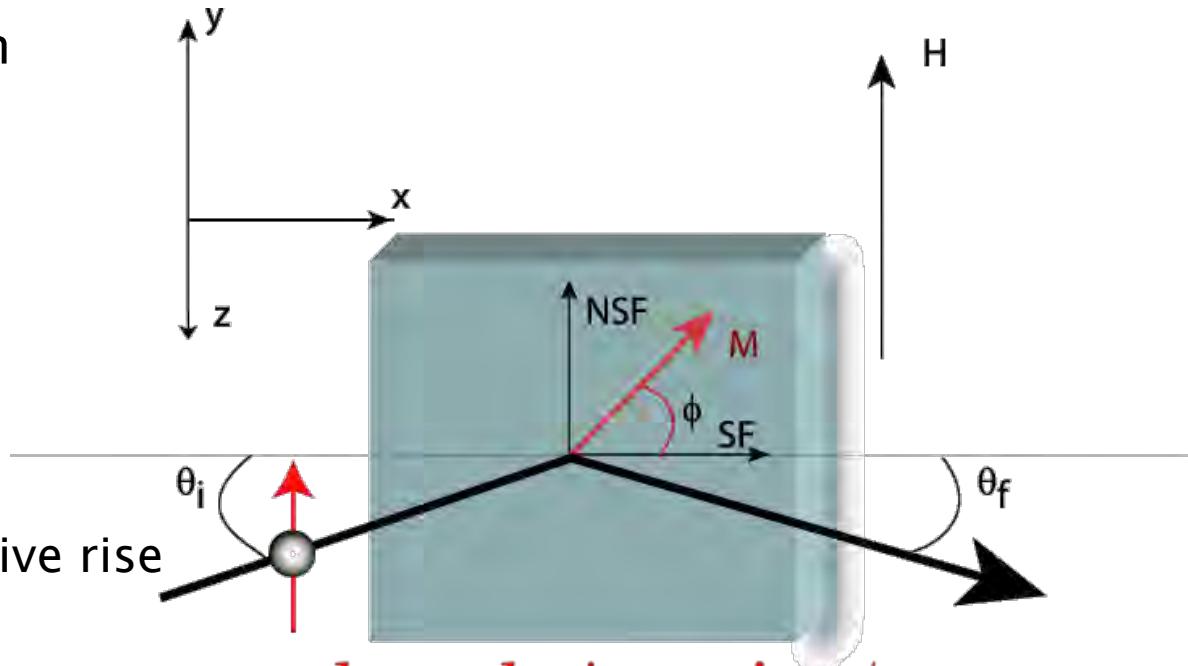
- Can observe the magnitude and orientation of atomic magnetic moments in thin films and multilayer media.
- Probe length scale (<1nm to >1000nm): covers many aspects of thin film structure and magnetism
- Complementary to:
 - VSM/SQUID
 - MOKE average magnetisation over the sample thickness
 - SEMPA, Lorentz surface domain magnetisation
 - XMCD/XRMS-element specific
- PNR gives the microscopic *in-plane vector* magnetisation *depth profile*.



Spin dependent cross-section

- In-plane orientation of magnetisation obtainable from 4 spin dependent cross-sections

- Components of the magnetisation, m give rise to
 - $m \parallel H$: Non Spin Flip Scattering (NSF)
 - $m \perp H$: Spin Flip Scattering (SF)
- Dynamical analysis gives absolute depth dependence profile



$$b = b + p \sin \phi$$

$$pm \cos \phi = px$$

$$\left[\frac{-\hbar^2}{2m_n} \nabla^2 + V(r) \right] \psi^{\uparrow,\downarrow} = E \psi^{\uparrow,\downarrow}$$

Small Angle Scattering

- Grazing Incidence to give depth selectivity
- Difference gives the interference term

$$\begin{aligned} I^+(Q, \alpha) &= \langle |F^{++}|^2 \rangle + \langle |F^{+-}|^2 \rangle \\ &= F_N^2 + (F_M^2 - 2PF_NF_M) \sin^2 \alpha \end{aligned}$$

$$\begin{aligned} I^-(Q, \alpha) &= \langle |F^{--}|^2 \rangle + \langle |F^{-+}|^2 \rangle \\ &= F_N^2 + (F_M^2 + 2PeF_NF_M) \sin^2 \alpha \end{aligned}$$

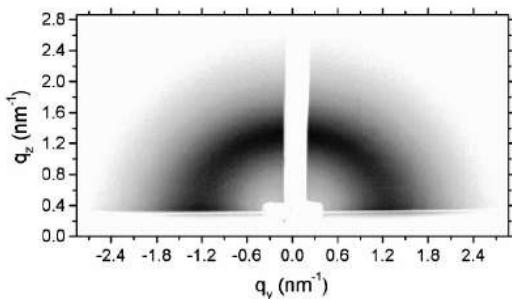


Figure 10

2D-GISAXS pattern of an $a\text{-C:H}/\text{Au}$ 8.2 at.% film using an imaging plate. The interference maximum (represented by a quasi-isotropic half ring) is related to the spatial correlation between isolated gold clusters embedded in the $a\text{-C:H}$ matrix. The z -direction is perpendicular to the film surface (from Babonneau *et al.*, 2001).

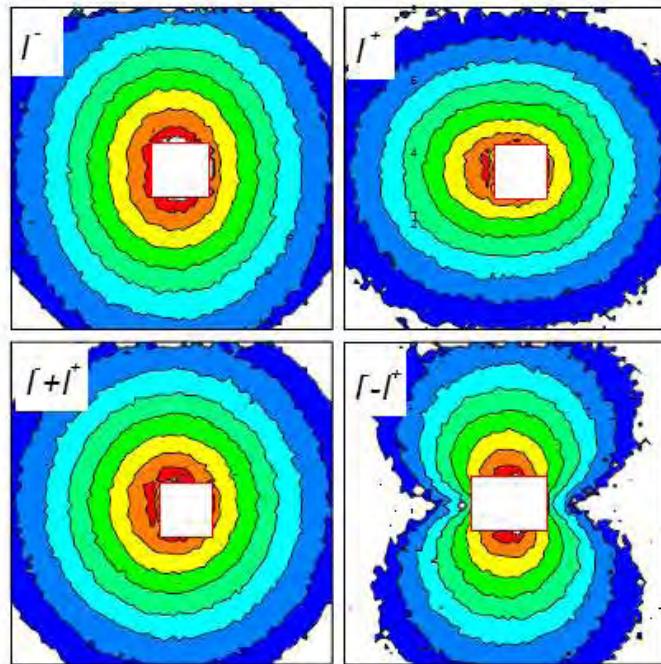


Figure 1

SANS-POL patterns in Fe_3O_4 for neutron spins antiparallel (I^-) and parallel (I^+) to the horizontal field. The arithmetic mean $[I^- + I^+]/2$ corresponds to the 2D pattern of non-polarised neutrons. The difference $I^+ - I^-$ yields the interference term [equation (1c)].

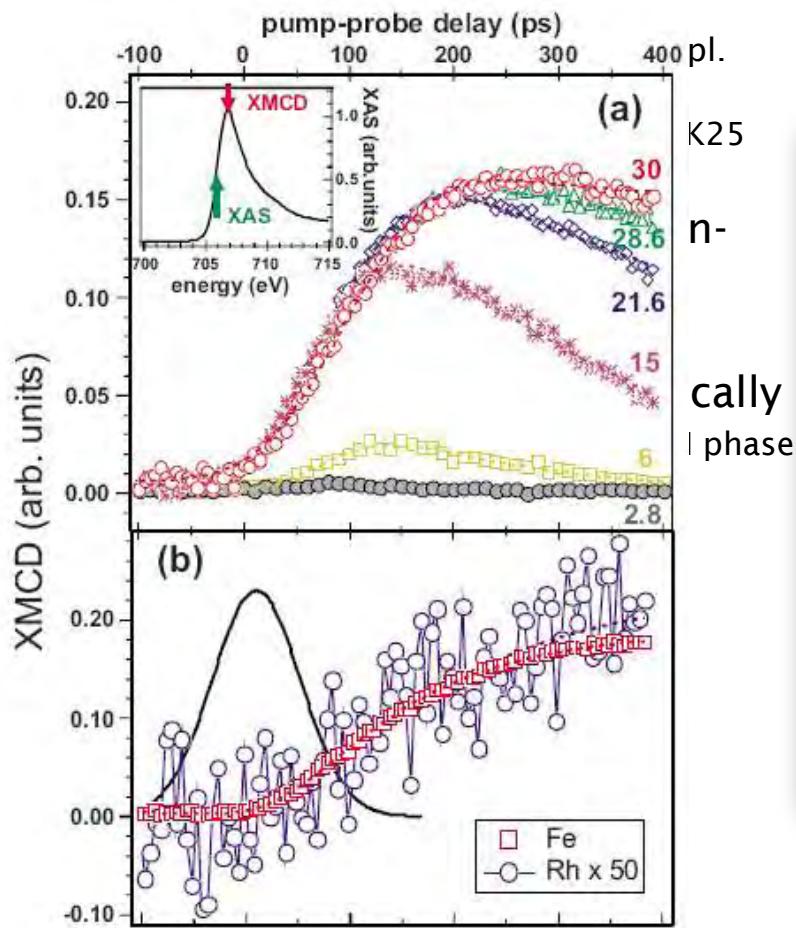
A Magnetostructural Phase Transition

FeRh epilayers



Motivation

Tunable Magnetostructural phase transition



FePt/FeRh system

Thiele *et al.* Appl. Phys. Lett. **82** 2859 (2003)

Control MTJ cell coercivity:

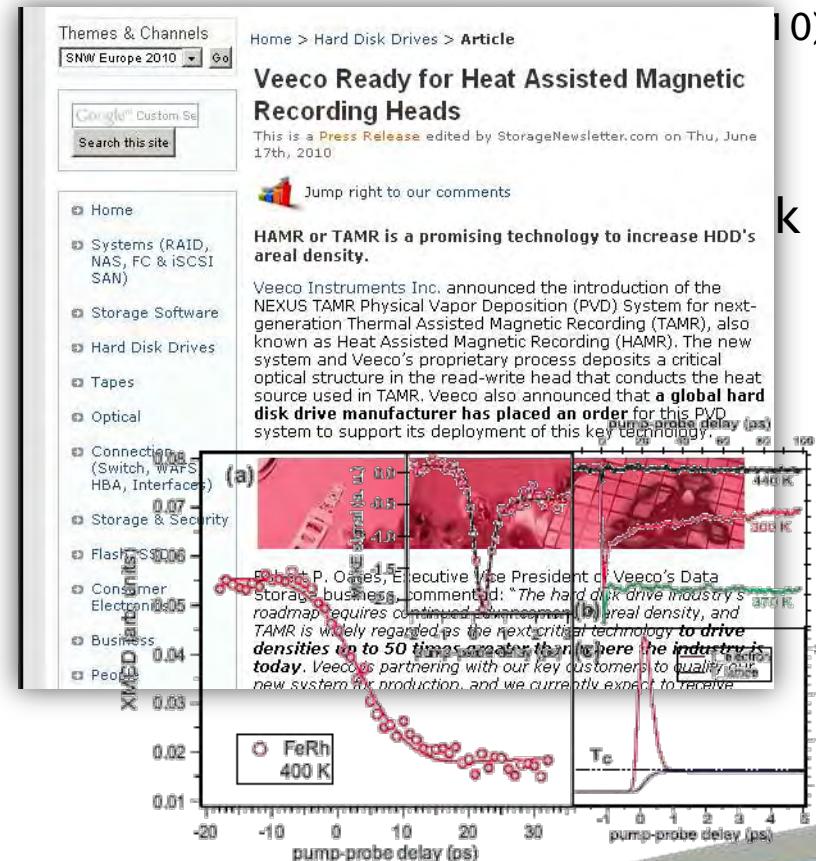
50Tb in²

Magnetic refrigeration

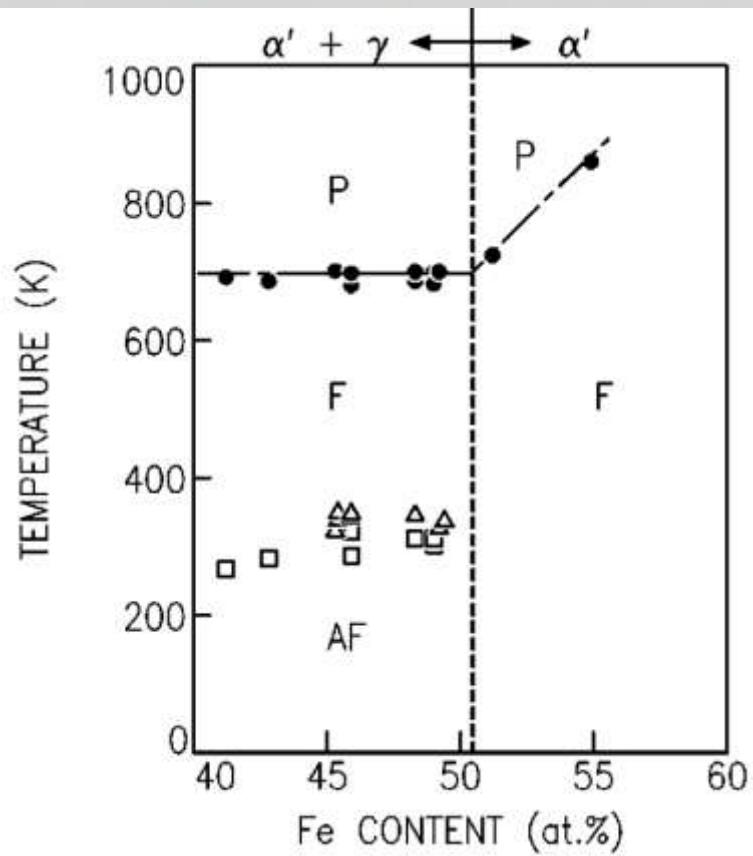
$\Delta S \sim 15 \text{ J Kg}^{-1} \text{ K}^{-1}$

Ultra-fast switching

Ju *et al.* Phys. Rev. Lett. **93**, 197403 (2004)



FeRh: Bulk Properties



- CsCl structure
 - $a \sim 2.99\text{\AA}$
 - α' phase
- Isostructural
- 300K: Type G AF
- Fe: $\sim 3.3 \mu_B$
- Rh: no moment
- FM alignment within $\langle 111 \rangle$ planes
- AF alignment between $\langle 111 \rangle$ planes
- 350 K: AF \rightarrow FM
- Fe: $\sim 3.1 \mu_B$
- Rh: $\sim 1 \mu_B$

- Van Driel et al., J. Appl. Phys. 85, 1026 (1999)
- Shirane et al. Phys. Rev. 134, A1547 (1964)

D. Arena, BNL

Sample Growth

- Base pressure: $\sim 5 \times 10^{-10}$ torr
- Combination of Knudsen cells and electron beam hearths
- Substrate: MgO(001)
- Composition: 48% Fe, 52% Rh
- Deposition at 300°C; post-growth anneal at 800°C for 60 min.
- Cap at 300°C with either Au, Ta or MgO
- Nominal FeRh thickness: 22, 50, & 100nm



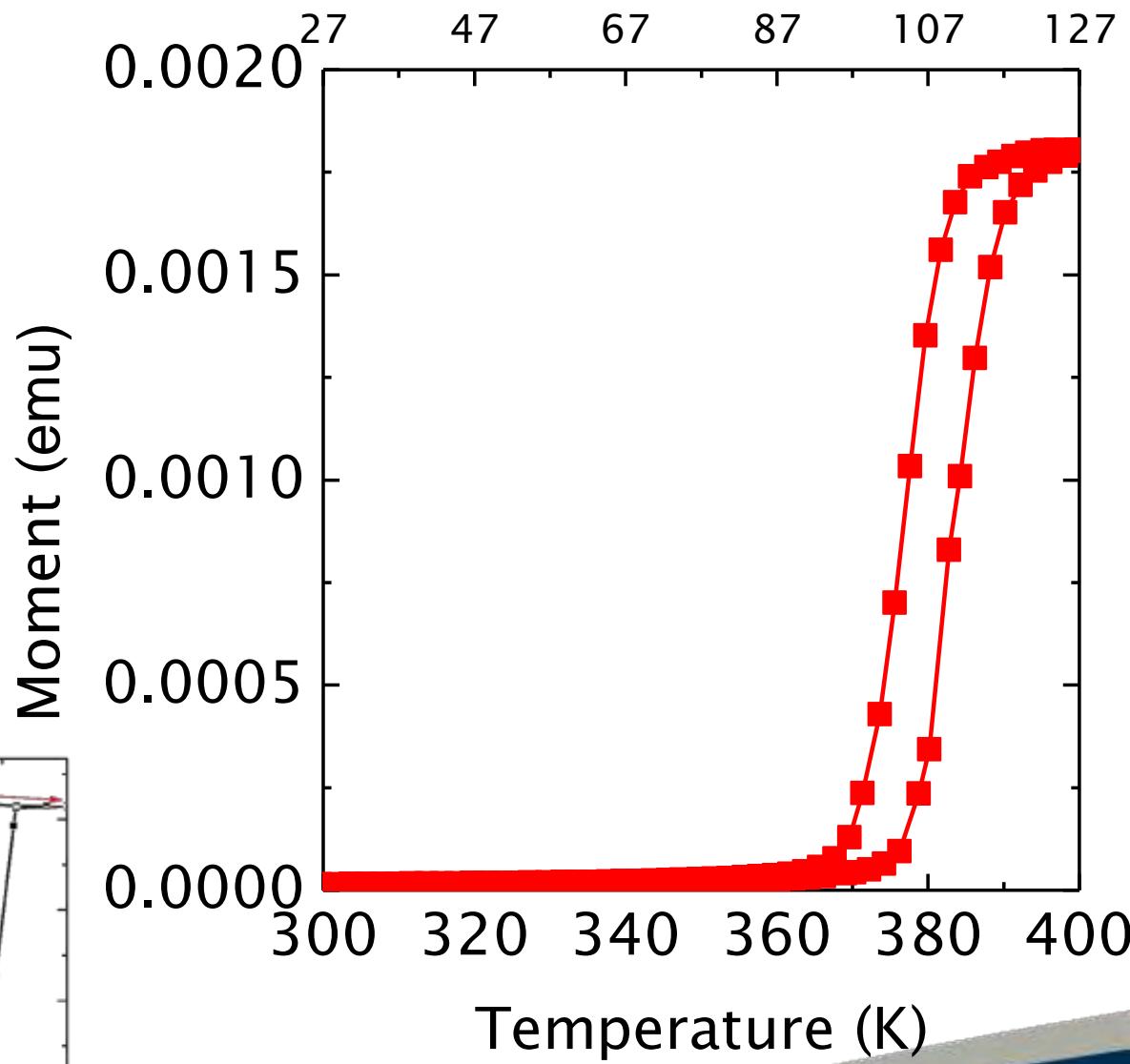
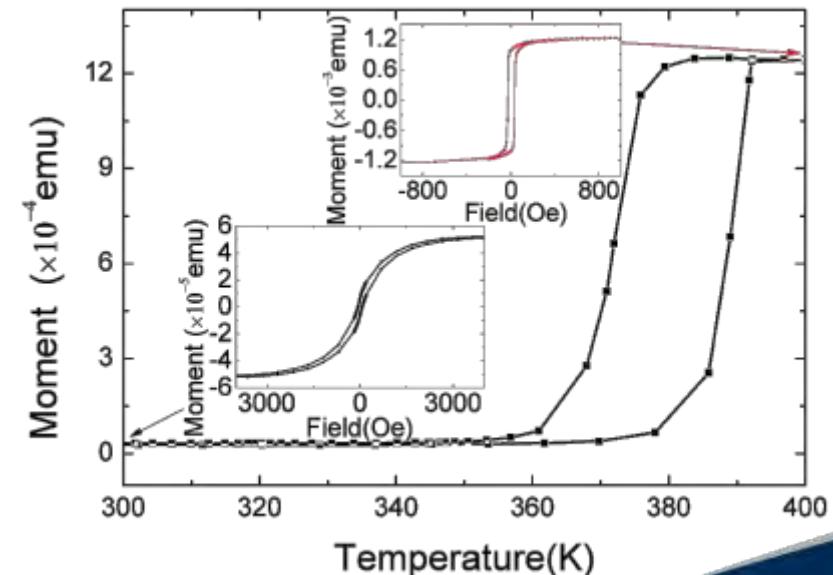
Magnetometry

SQUID

- $T_{AF-F} \sim 375K$
- 10K Hysteresis
- $H=5100e$
- Field lowers transition temperature
- $T=400K$

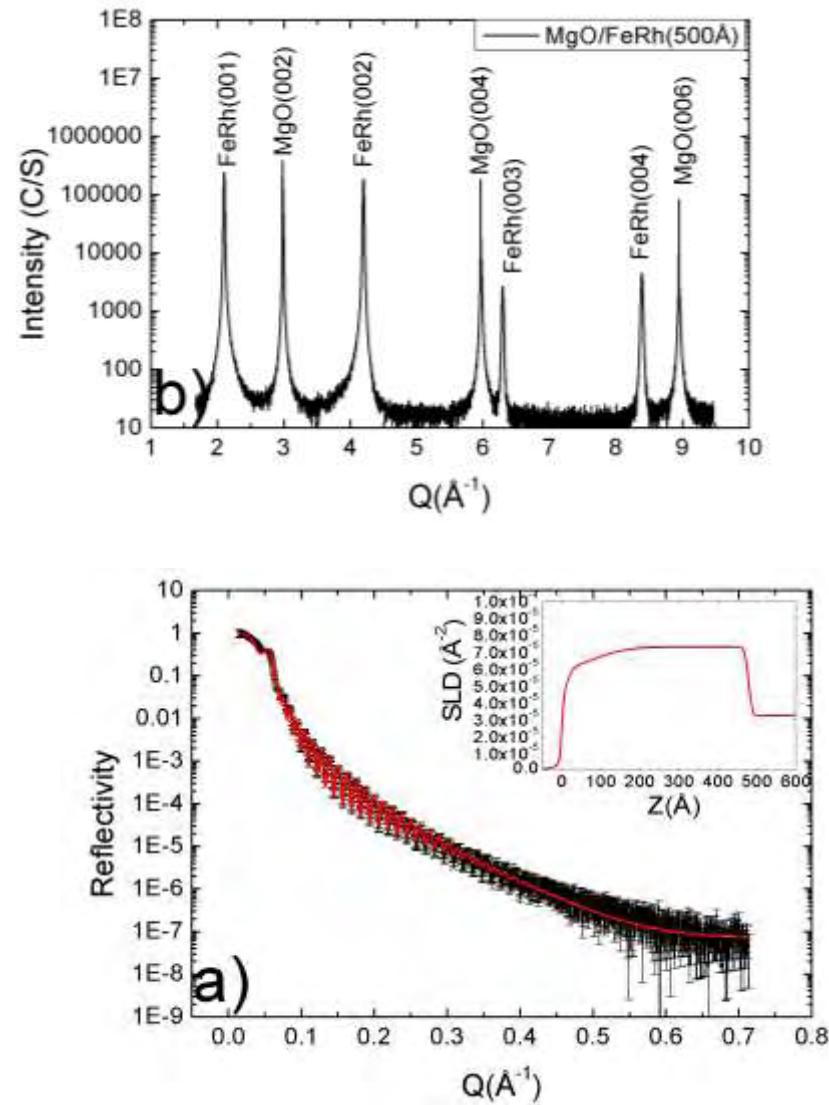
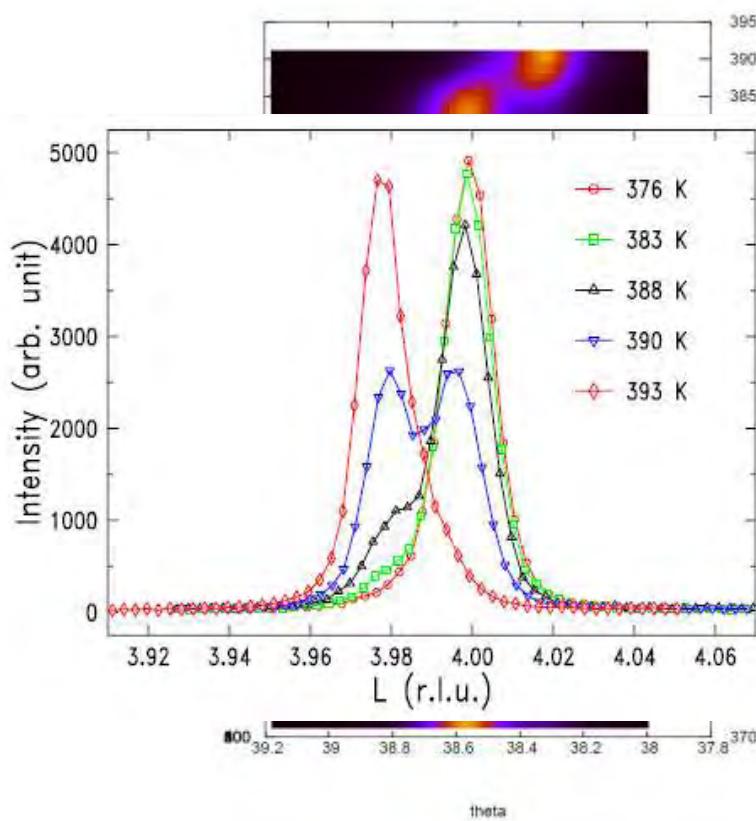
$$H = - \sum_i D_i S_i^2 - \sum_{\langle nn,nn \rangle} J_{ik}(r_{ik}) S_i S_k$$

$$+ \sum_{\langle nn \rangle} V_{nn}(r_{ik}) + \sum_{\langle nnn \rangle} V_{nnn}(r_{ik}).$$



Structural

- Au/FeRh[50nm] (002)
- FeRh<001> || MgO<110>
- $a = 2.998\text{\AA}$



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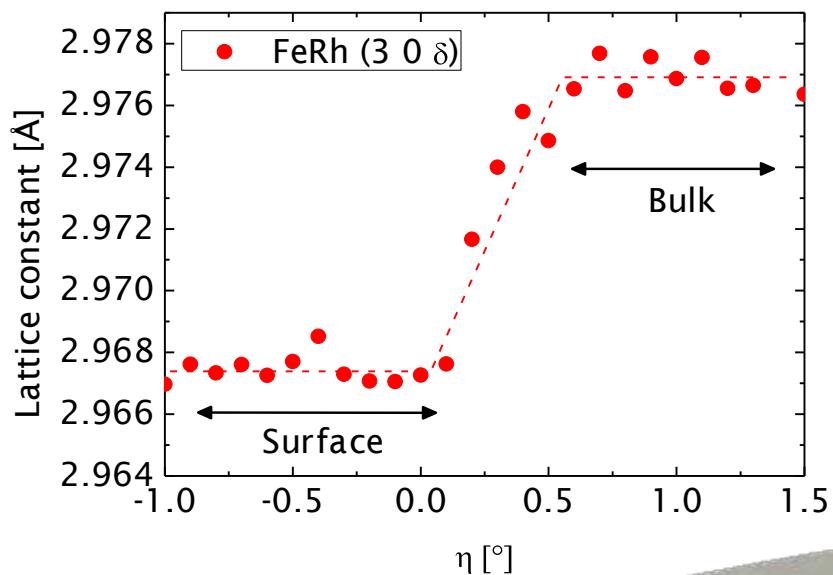
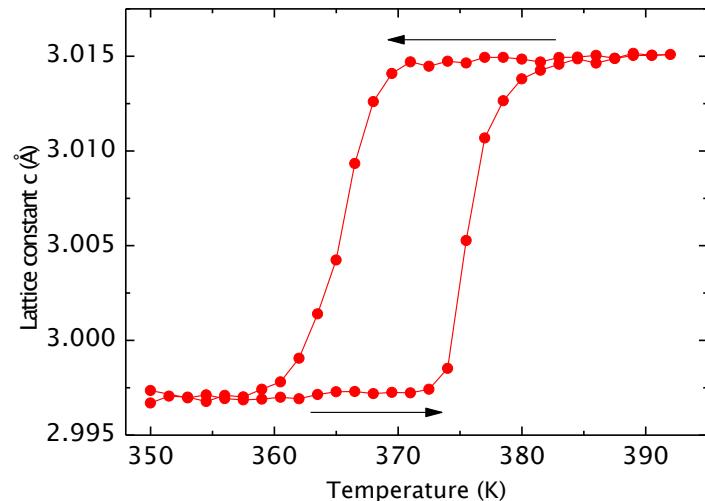
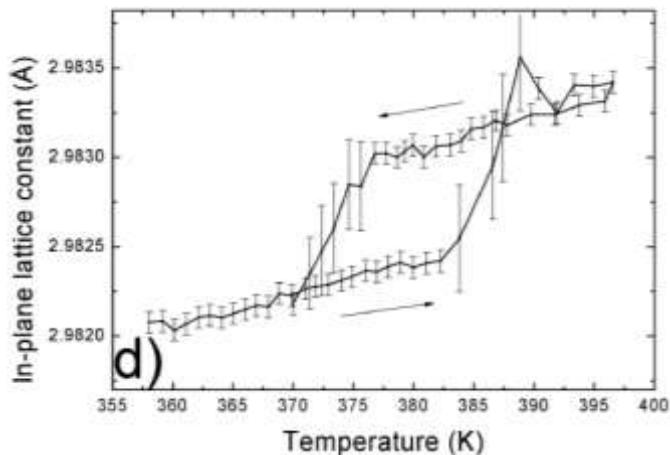
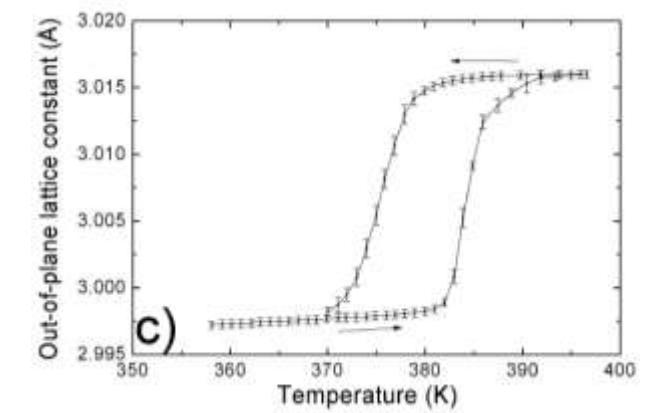
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Surface Diffraction

■ RT

- Surface: 2nm
- Bulk: 200nm



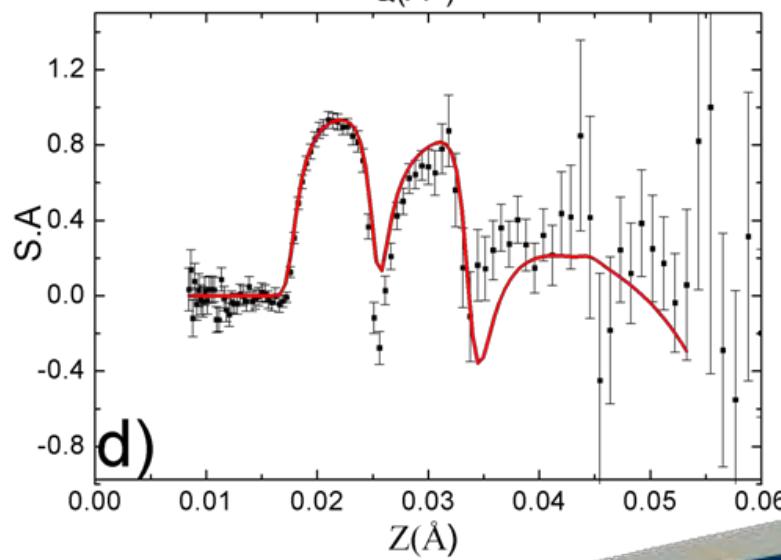
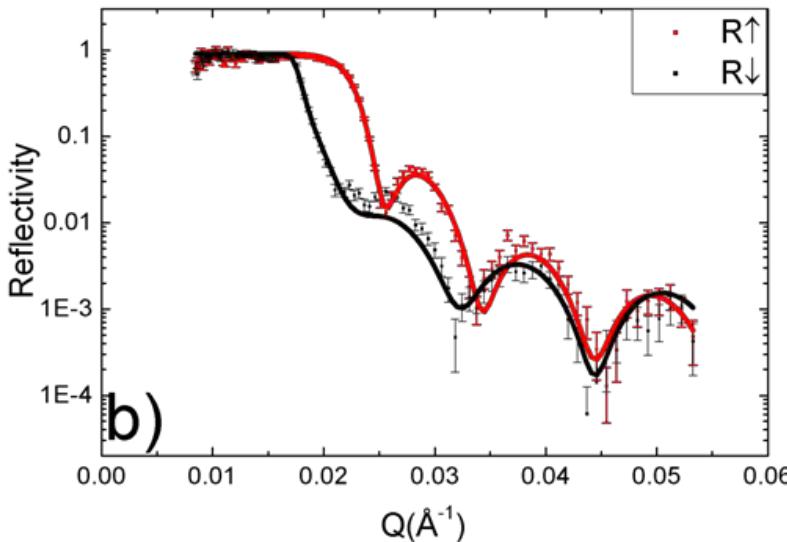
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MgO[2]FeRh[50]/MgO

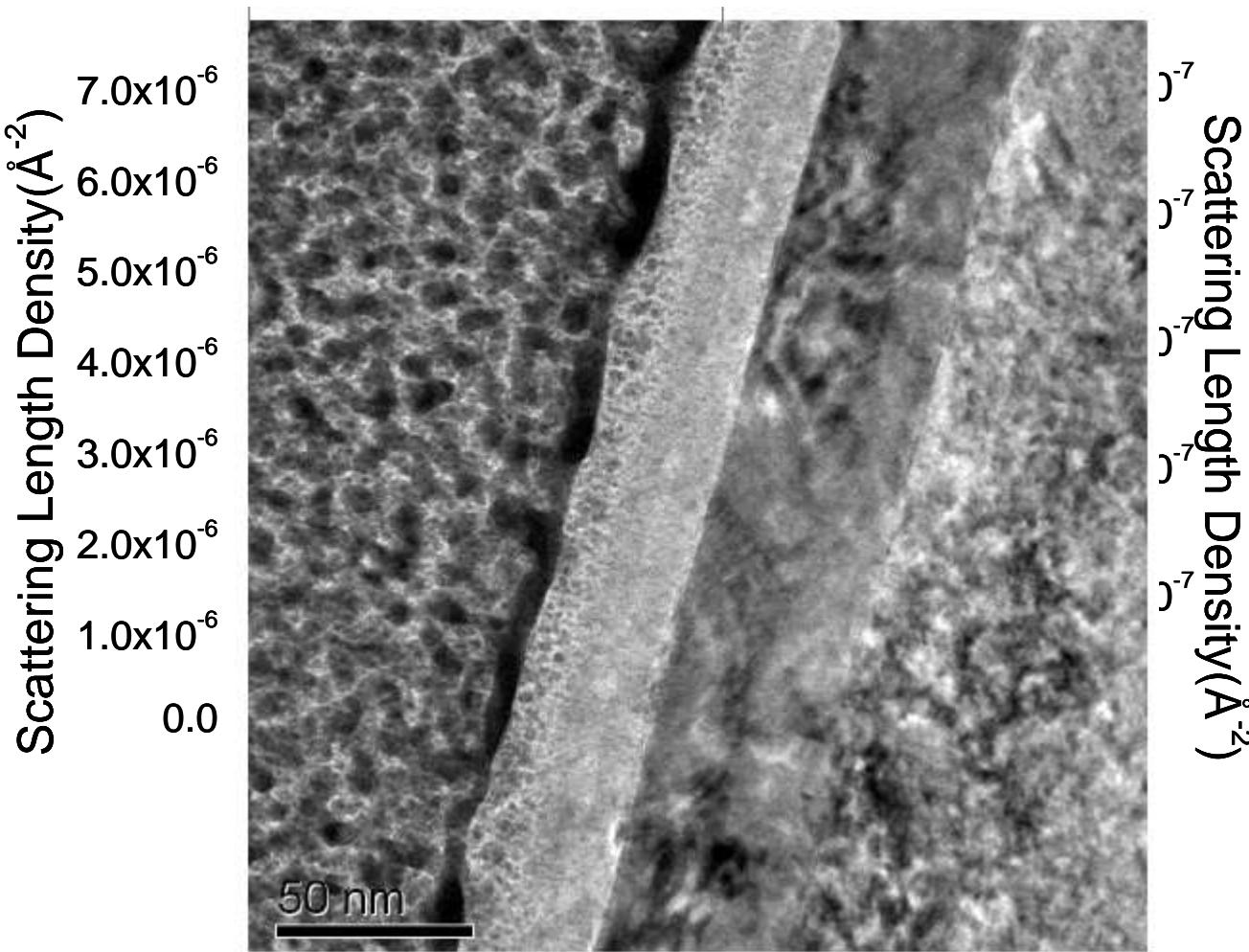
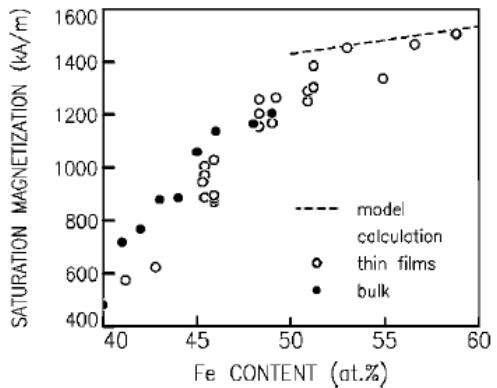
$$R = (I^+ - I^-)/(I^+ + I^-)$$



- I. Suzuki *et al.* J. Appl. Phys. 105, 07E501 (2009)
- Fan *et al.* prb 82 184418 (2010)

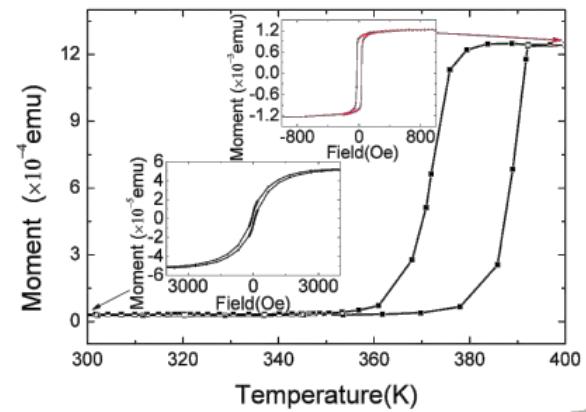
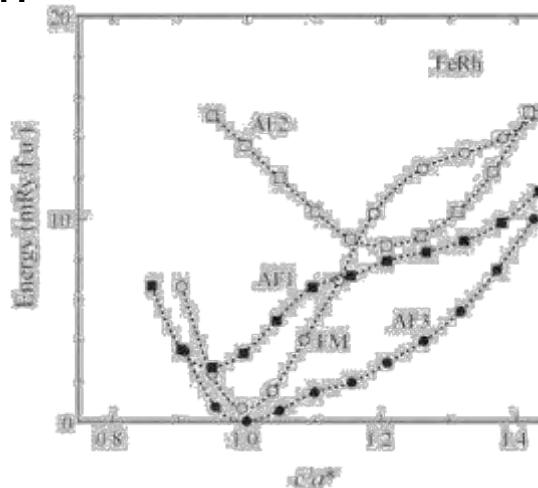
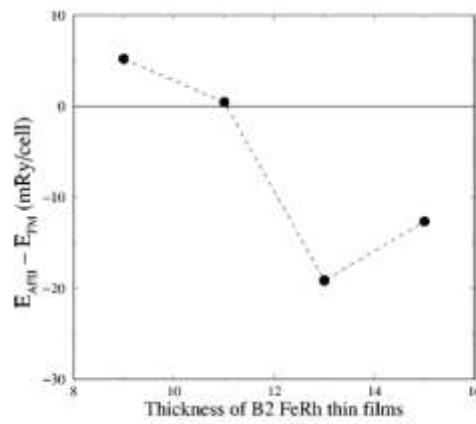
Magnetic profile

- MgO -0.5%
- Clear evidence of RT FM
 - 0.08 μ B
 - 1.56 μ B @400K
- Rh rich surface
 - Reduced moment in FM phase
 - Reduced ordering temperature



Origin of ferromagnetism...

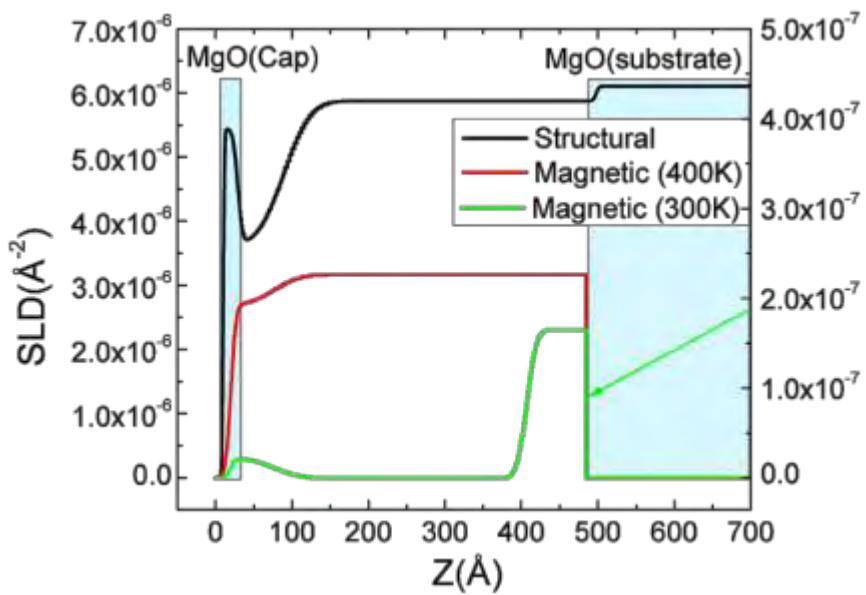
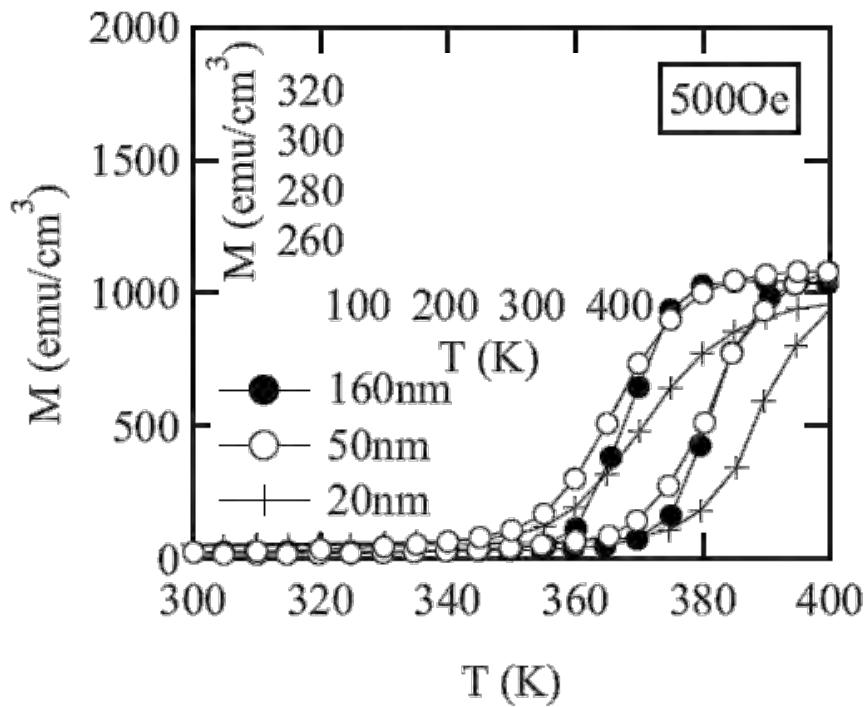
- Mix of α and γ phases
 - Complex surface structure (Rh rich)
 - Favours reduction in AF-FM transition
- In-plane compression
 - Suppress the transition *viz* high pressure
 - Breaking of cubic symmetry
- Fe/Rh termination



- Suzuki *et al.* *japl* 105, 07E501 (2009)
- Lounis *et al.* *prb* 67 094432 (2003)
- Yamada *et al.* *jac* 415 31 (2006)

Ultra-thin FeRh

- PNR gives $230 \times 10^3 \text{ Am}^{-1}$
- Domain distribution studies



- Suzuki *et al.* *japl* 105, 07E501 (2009)
- Lounis *et al.* *prb* 67 094432 (2003)
- Yamada *et al.* *jac* 415 31 (2006)

Nanoscale Superconductivity



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DoE priorities

■ Superconductivity Applications

- Developing HTS-based electric power equipment such as transmission and distribution cables and fault current limiters

■ Second-Generation Wire Development

- Developing high-performance, low-cost, second-generation HTS wire at long lengths

■ Strategic Research

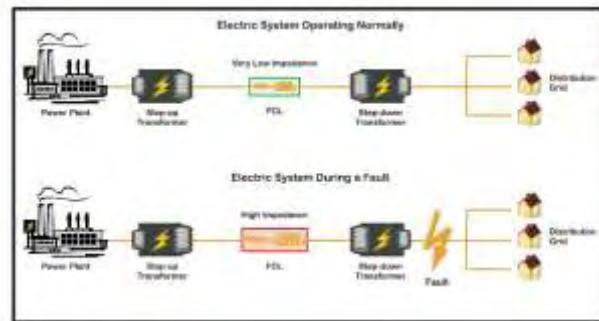
- Supporting fundamental research activities to better understand relationships between the microstructure of HTS materials and their ability to carry large electric currents over long lengths

■ Applications

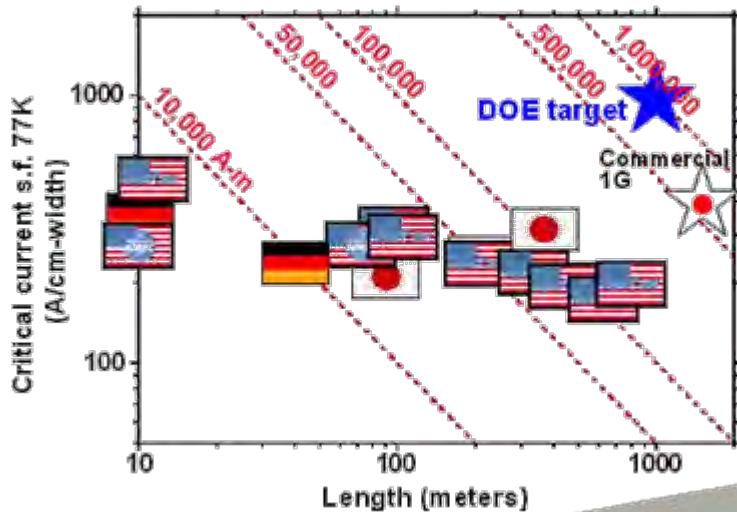
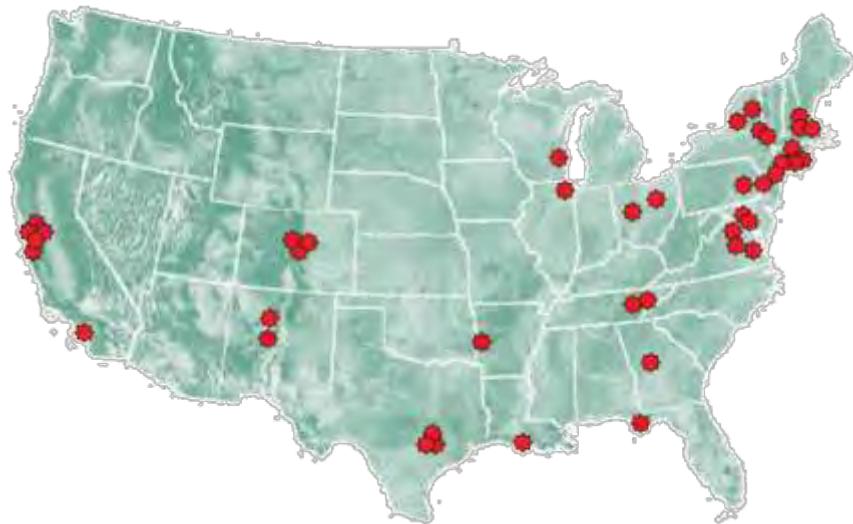
- SC Generators
- SC Energy Storage Systems
- SC Power Cables

■ Relevance of Neutron measurements

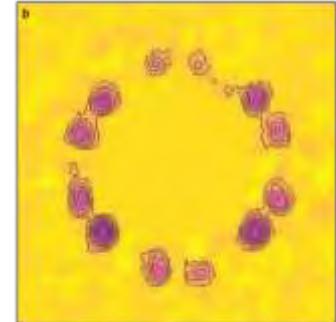
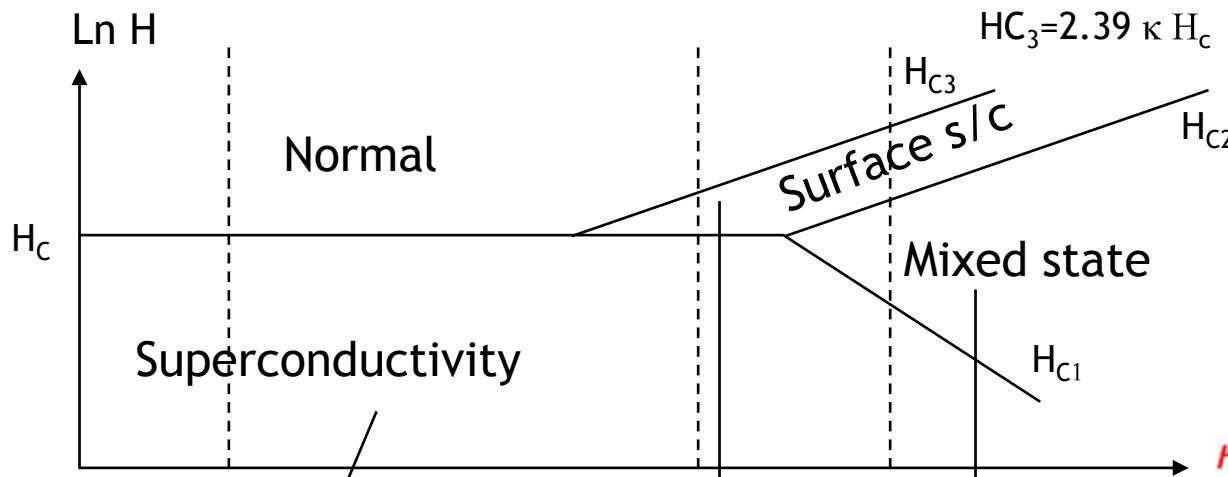
- Proximity effects
- Flux penetration
- Nonlocal effects
- FLL
- Control of T_c
- Importance of Interfaces



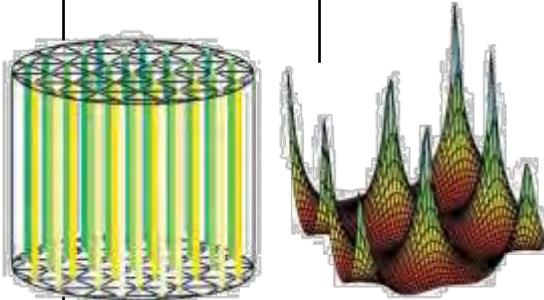
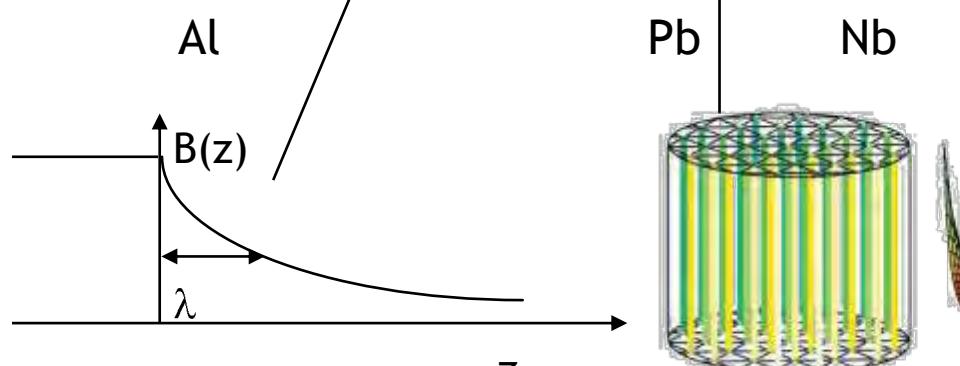
■ <http://www.oe.energy.gov>



Flux penetration in superconductors

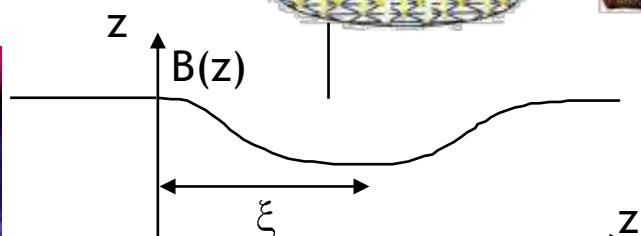
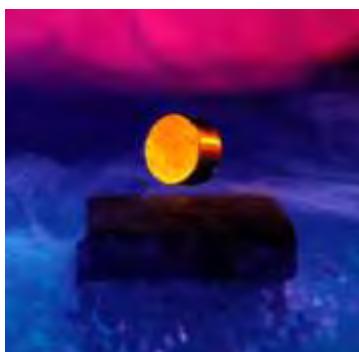


R.J. Cubitt *et al*
Phys. Rev. Lett. **91**
047002 (2003)



$$\kappa = \frac{\lambda}{\xi}$$

- $H < H_c$ magnetic induction vanishes except within a penetration depth λ
- $H > H_c$ destroys bulk s/c and magnetic flux penetrates sample
- $H_{c3} > H > H_{c2}$ surface s/c approximately equal to the coherence length, ξ
- Pb $T_c = 7.2\text{K}$, $H_c = 8000\text{Oe}$



Flux penetration in superconductors

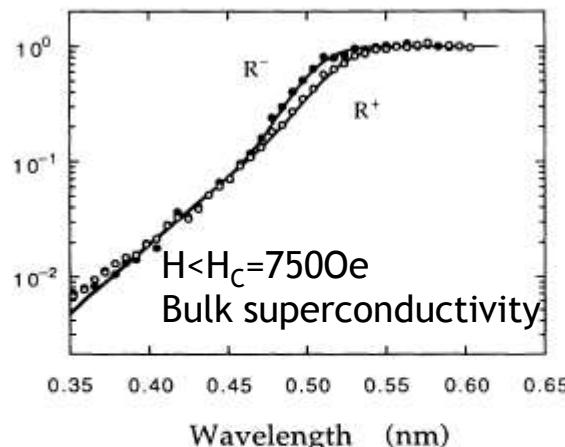


FIG. 2. The spin-dependent reflectivities R^+ and R^- measured in an applied magnetic field of 6.0×10^4 A/m (750 Oe). The continuous lines are the reflectivities calculated for the two polarization states, with the same instrumental and surface parameters as in Fig. 1, and an exponential decay of magnetic induction with a penetration depth of 39 nm.

PHYSICAL REVIEW B

VOLUME 49, NUMBER 22

11

Magnetic-induction profile in a type-I superconductor by polarized-neutron reflectometry

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TABLE I. Literature results for the penetration depth of lead referred to absolute zero. Only the values for the actual penetration depths, $\lambda(0)$, are given even though in some techniques the measured quantity relates more naturally to the London penetration depth, $\lambda_L(T)$, at temperatures close to T_c .

Technique	$\lambda(0)/\text{nm}$	Ref.
Absolute surface impedance	~ 54	28
Magnetization of thin films	39 ± 3	29
Perpendicular field transition	~ 44	30
Surface impedance	$\sim 48^a$	31
Quantum interference in thin film	51-56	32
Field attenuation in thin film	45.3 ± 8	33
Surface impedance in a field	~ 42	34
Absolute surface impedance	48 ± 4	35
Inductance	~ 52.5	36
Polarized neutron reflectometry	39 ± 1	This work

^aOnly $\lambda_L(0)$ is given explicitly in Ref. 31, but the results for $\lambda(T)$ obtained by a strong-coupling calculation are shown graphically in Fig. 1, and the value $\lambda(0) \approx 48$ nm cited here has been taken from this graph.

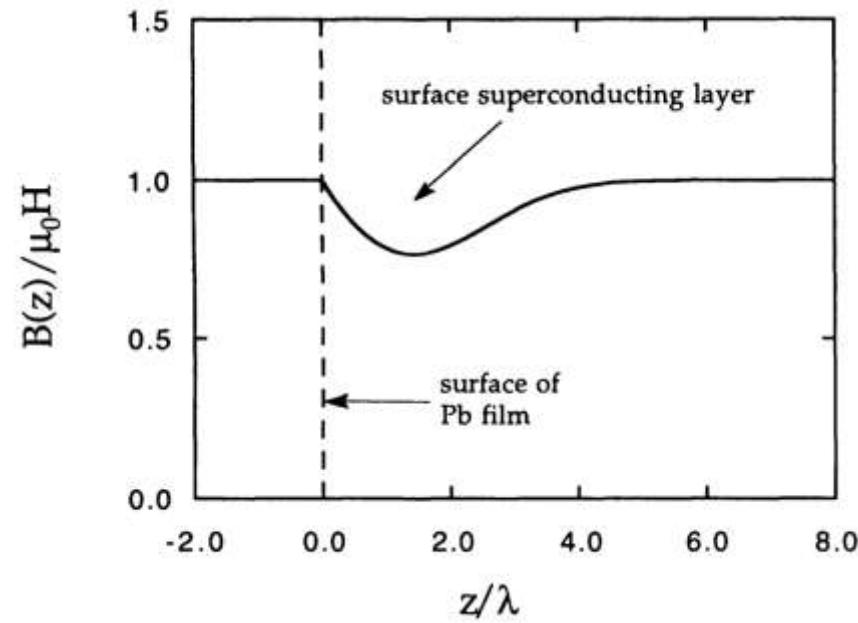
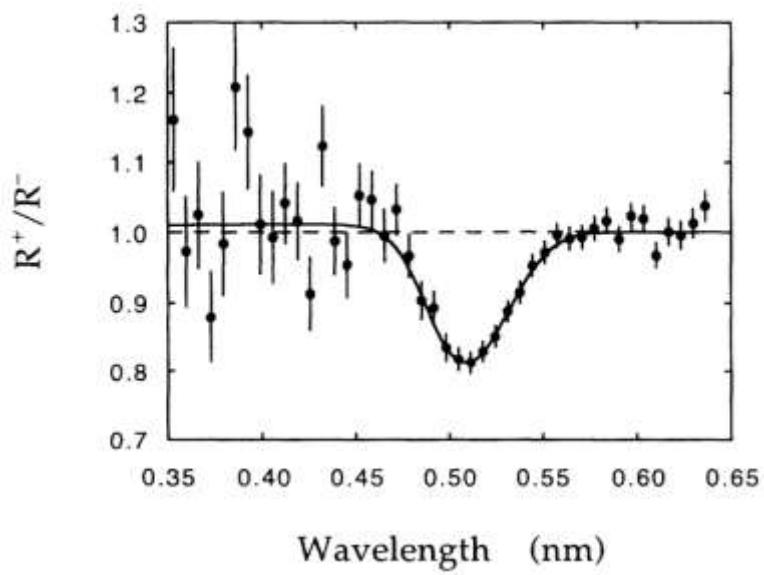
INO TIELA
dependence



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$$H_c < H < H_{c3}$$



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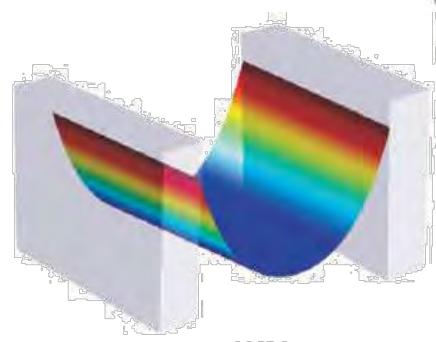
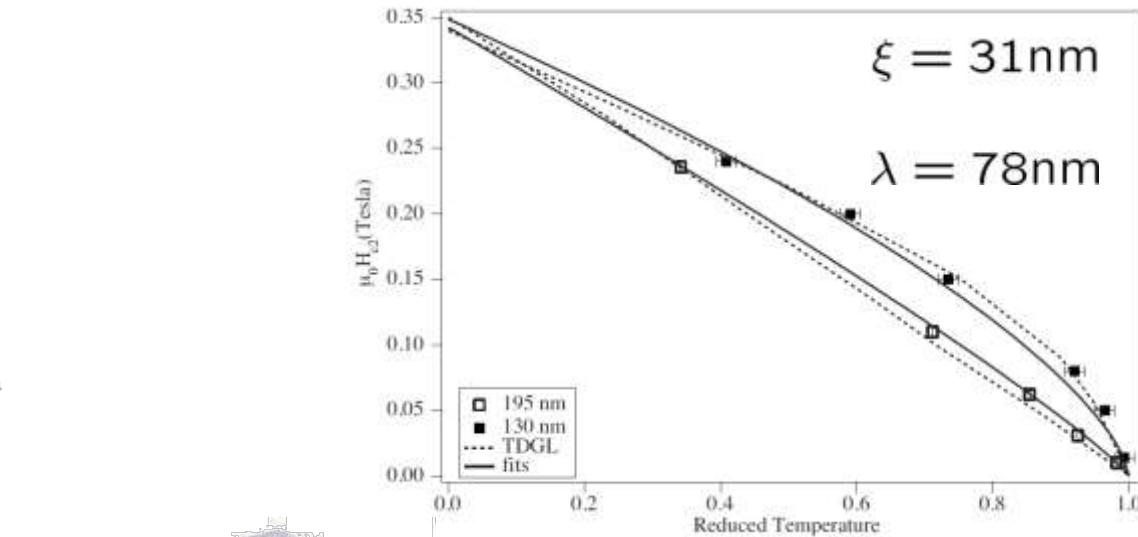
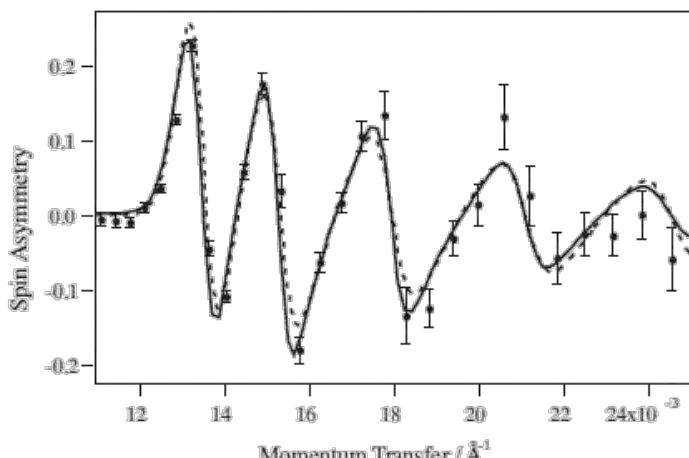
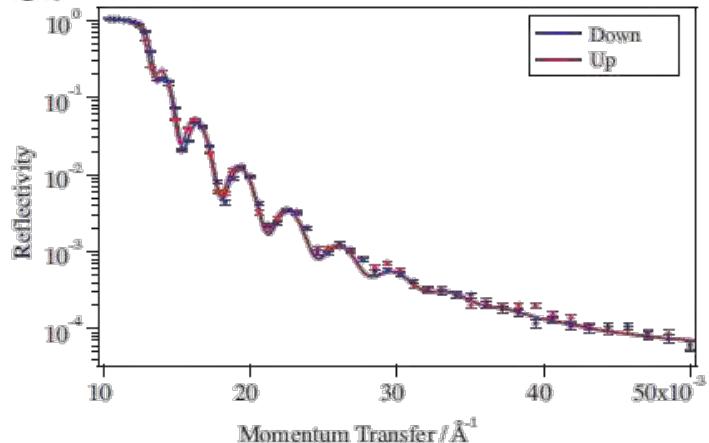
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TDGL

$$\frac{\partial \psi}{\partial t} = \frac{-1}{\eta} [(-i\nabla - \mathbf{A})^2 \psi + (1-T) (|\psi|^2 - 1) \psi] + f$$

$$\frac{\partial \mathbf{A}}{\partial t} = (1-T)\mathcal{R} [\psi^\star (-\nabla - \mathbf{A}) \psi] - \kappa^2 \nabla \times \nabla \times \mathbf{A}$$



$$B(y) = \mu_0 H_E \frac{\cosh\left(\frac{2y-d}{\lambda}\right)}{\cosh\left(\frac{d}{2\lambda}\right)}$$



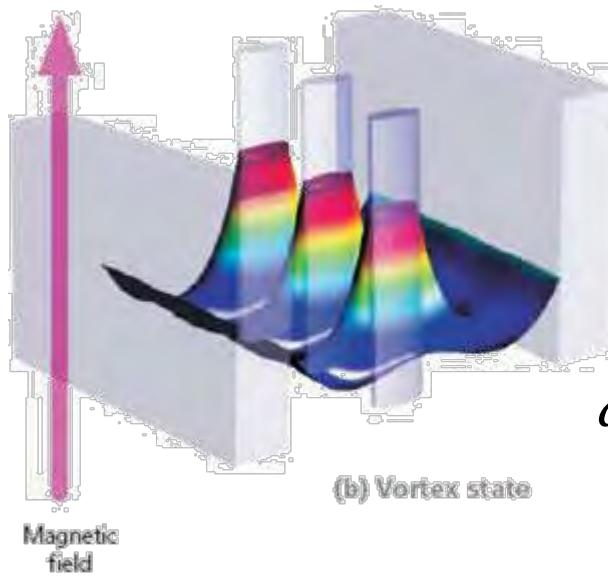
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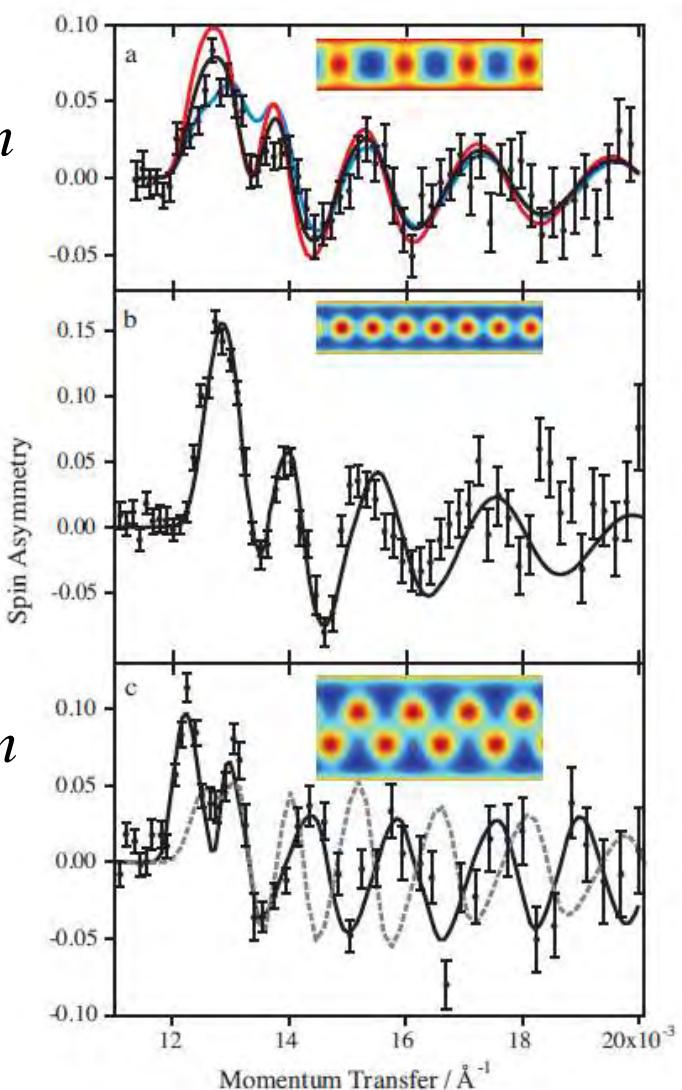
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Flux distribution

$d = 195\text{nm}$



$d = 250\text{nm}$



Magnetism and high temperature superconductivity

LETTERS

Magnetism at the interface between ferromagnetic and superconducting oxides

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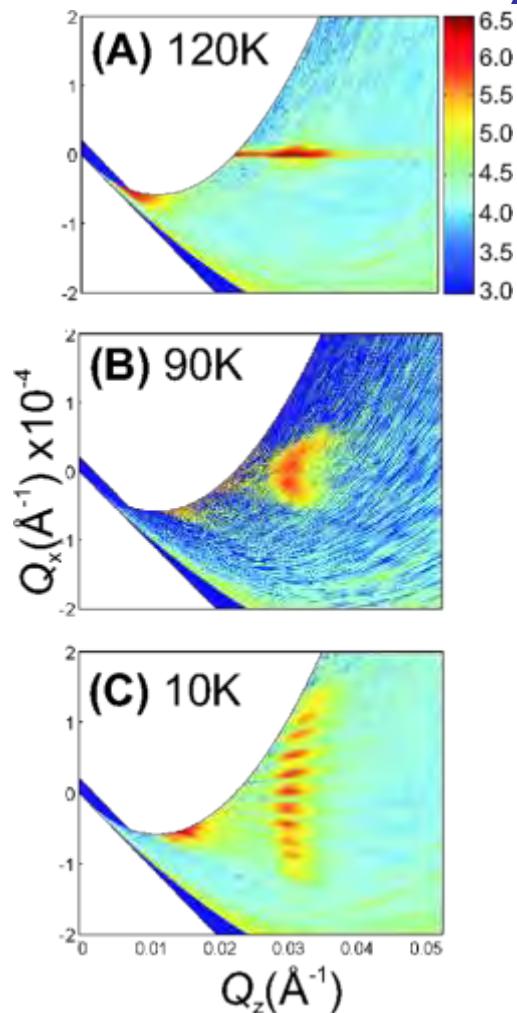
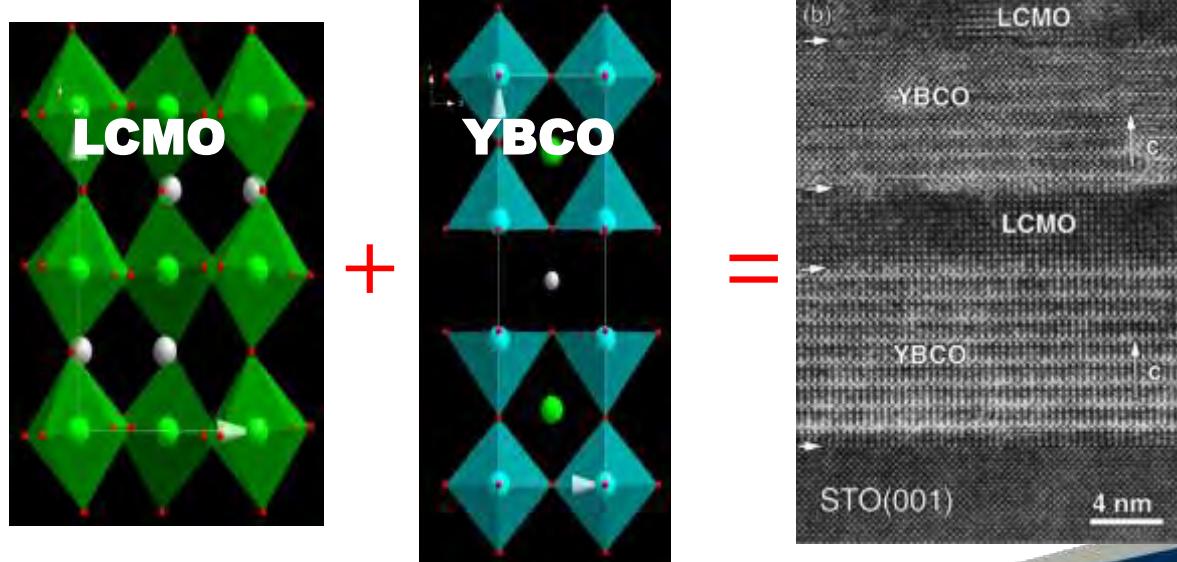
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nature physics | VOL 2 | APRIL 2006 |



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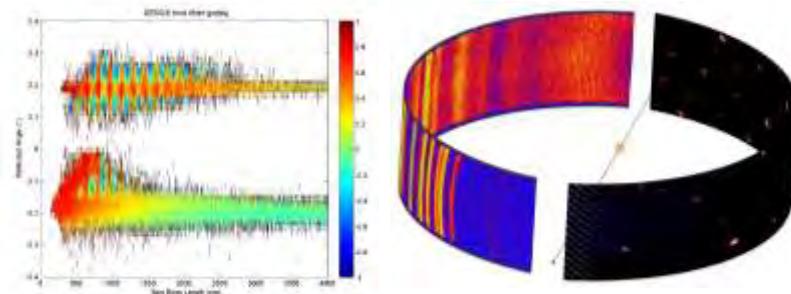
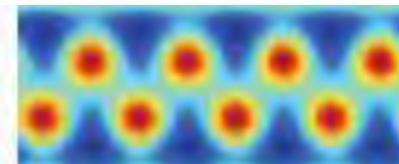
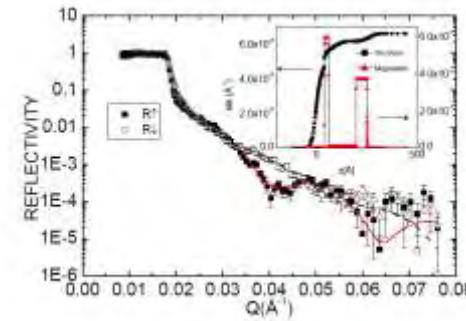
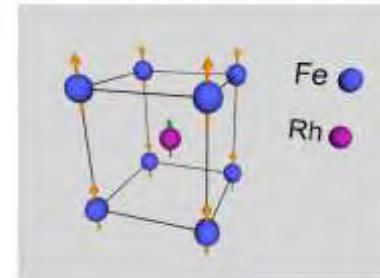
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Outlook I



- Interfacial phenomena offer the possibility of controlling magnetism
 - Magnetostructural transitions
 - Spin Accumulation
 - Dilute magnetic semiconductors
 - Hybrid magnetic/superconducting systems
 - Multiferroics ...
- Quantitative test of theory
- Interface Sensitive
- Dynamics/Kinetics
- Applicable to a wide class of nanoscale phenomena
 - Proximity effect
 - Dead layers
 - Vortex Structures (Reflectometry & SANS)



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Outlook II

- Sensitive & powerful techniques to spatially resolve the magnetism and superconductivity in nanoscale systems



Target Station 1



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